

13th International Workshop on Plasma-Facing Materials and Components for Fusion Applications /1st International Conference on Fusion Energy Materials Science

Comparison of deuterium retention for ion-irradiated and neutronirradiated tungsten

Y. Oya^{a,*}, M. Shimada^b, M. Kobayashi^a, T. Oda^c, M. Hara^d, H. Watanabe^e, Y. Hatano^d, P. Calderoni^b and K. Okuno^a ^a Radioscience Research Laboratory, Faculty of Science, Shizuoka University, JAPAN ^b Fusion Safety Program, Idaho National Laboratory, USA ^c School of Engineering, The University of Tokyo, JAPAN ^d Hydrogen Isotope Research Center, University of Toyama, JAPAN <u>e Institute for Applied Mechanics, Kyushu University, JAPAN</u>







Background

- Plasma facing components research for fusion applications has recently focused on tungsten materials due to low sputtering yield and low tritium retention. One of the key issues under performance evaluation of plasma facing materials is tritium retention and recycling under fusion relevant conditions.
- Recently, high energy ion irradiation experiment was performed on tungsten to demonstrate neutron irradiation effect on tritium retention.

Objective of this research

- The objective of this research is to understand the tritium behavior in neutronirradiated materials for fusion first walls (trapping of tritium by defects formed by neutron irradiation) under Task2-1 (Irradiation-Tritium synergism) of Japan-US collaboration program (TITAN).
- Comparison of tritium behavior in ion irradiated materials will help the understanding of neutron irradiation effects on tritium retention behavior.
- Simulation research works using TMAP and Monte Carlo code are also performed to understand the neutron irradiation effect on tritium behavior.

Research Scheme



Tritium Plasma Experiment (TPE) at INL

Linear type plasma

- LaB₆ source and actively water-cooled target
- Steady state plasma up to high fluence (~10²⁶ m⁻²)
- High flux (~10²² m⁻²s⁻¹), surface temp. (300~1000K)

Tritium use:

- Tritium inventory in STAR: <15000 Ci (1.5g)
- * (0.1 ~ 3.0 %) T₂/D₂

Double enclosures for tritium use

- System piping as primary confinement
- Glovebox as a ventilation hood (second enclosure)
- PermaCon box as a third enclosure
- Ubeds as tritium getter
 - Estimate take of each U bed (²³⁸U: 1.27kg)
 - * UX₃ (x=H,D,T) ~ 8 mole of X_2
 - * 1% T₂/99%D₂: 0.08 mole ~0.5g ~5000 Ci

Activated material handling in STAR

- Dose rate: < 100 mrem/hr (1 mSv/hr) at 30cm</p>
- Radioacitivity: less than HC 3 limit

Jaho National Laboratory

TPE chamber schematic Solenoid Magnets sample Pancake W heate Magnets aBe cathode GP: convection gauge LP: capacitance manomete Gate valve IG: ion gauge RGA: residual gas analyze TMP: turbo molecular pump RP: roughing pump TPE target assembly TPE source assembly TC (type K) Cu w/ H₂O cooling Ta cathode hold H₂O cooling heat sink material cathode power (Cu, SS, Ni, various shape) TPE schematic GP4 Ώov MSB1 Exhaust Stack U Beds 🔄 : manual valve Glove Box Boundary pneumatic valv

Development of experimental techniques





Sample Holder for Tritium Plasma Experiment, Idaho National Laboratory





Thermal Desorption System

TEM image for tungsten before irradiation



W : stress relived condition (900 K)

No defects were observed. Only the grain boundaries were found.

Surface morphology for Cu²⁺ irradiated W observed by TEM



0 dpa : Only small amount of dislocation was observed.

0.03 dpa : A large number of dislocation loops with the size less than 10 nm was dispersedly confirmed.

0.3 - 3 dpa : The density of dislocation loops was enhanced as the number of dpa (irradiation fluence) was increased and the nucleation of dislocation loop was found.

Summary of D plasma exposure conditions at TPE

Sample	Fe imp W 0.025 dpa	Fe imp W 0.3 dpa	Fe imp W 3 dpa	n-irradiated W 0.025 dpa	Un-implanted W
Target current	2.3 A	2.3 A	2.8 A	2.4 A	2.6 A
Flux	9.0 X 10 ²¹	8.2 X 10 ²¹	1.0 X 10 ²²	5.0 X 10 ²¹	6.5 X 10 ²¹
Exposure Time	6300 s	7200 s	6300 s	7200 s	9600 s
Fluence	5.7 X 10 ²⁵	5.9 X 10 ²⁵	6.0 X 10 ²⁵	3.6 X 10 ²⁵	6.2 X 10 ²⁵
Electron density	9.6 X 10 ¹⁷	7.5 X 10 ¹⁷	1.1 X 10 ¹⁸	4.0 X 10 ¹⁷	5.4 X 10 ¹⁷
Electron temperature	8.2 eV	7.7 eV	5.5 eV	9.0 eV	7.6 eV
Bias energy	-100 eV				
lon energy	~100 eV				
Sample Temperature	473 K				

TDS spectra for neutron irradiated W and ion implanted W



The peaks of TDS spectrum for ionimplanted samples were concentrated in the lower temperature less thank 700 K. Un-irradiated sample (0 dpa) The desorption stage was only observed at 550 K.

Ion-irradiated samples (0.025-3 dpa) The additional peak was found at lower temperature side.

The D desorption was increased as the number of dpa increased.

The oxidized sample (673 K 2 hour) The desorption stage was the same as the un-irradiated sample. The D accumulation was due to the surface trapping and/or diffusion barrier.

TDS spectra for neutron irradiated W and ion implanted W



D₂ TDS spectra for n-irradiated W and ion implanted W

- The peaks of TDS spectrum for ionimplanted samples were concentrated in the lower temperature less thank 700 K.
- It looks like the TDS spectrum for LTS sample for Reference.



Figure 9. Thermal desorption spectra for irradiated (2 dpa) and unirradiated (0 dpa) W targets in the low-temperature (LTS) and HTSs.

The additional desorption peak was found for neutron-irradiated samples, which is almost the same as the HTS (2 dpa), but the ion-irradiated sample with 3 dpa does not show this higher desorption.

G. M. Wright, et al., Nucl. Fusion 50 (2010) 075006.



≻Two desorption peaks were observed for ion implanted W and oxidized one. However, that for neutron irradiated one was consisted of more than three stages.

- >Deuterium retention in both peaks increased as the number of dpa increased.
 - (Peak 2 was remarkably increased)

➤The TDS spectrum for oxidized sample does not show the additional desorption peak, showing that no surface effect for D trapping.

> Peak 3 was only appeared for n- irradiated W.



D₂ TDS spectrum for damaged W

➤Two desorption peaks were observed for ion implanted W and oxidized one. However, that for neutron irradiated one was consisted of more than three stages.

- >Deuterium retention in both peaks increased as the number of dpa increased.
 - (Peak 2 was remarkably increased)

>The TDS spectrum for oxidized sample does not show the additional desorption peak, showing that no surface effect for D trapping.

> Peak 3 was only appeared for n- irradiated W.

Comparison of D retention for various W samples

Sample ID	Temperature	D fluence [D m ⁻²]	D retention [D m ⁻²]	ratio (retained/implanted)
Neutron irradiation (0.025 dpa)	473 K	3.6 X 10 ²⁵	2.17 X 10 ²¹	6.03 X 10 ⁻⁵
Ion implantation 3 dpa	473 K	6.0 X 10 ²⁵	3.10 X 10 ²¹	5.17 X 10 ⁻⁵ 3 times
lon implantation 0.3 dpa	473 K	5.9 X 10 ²⁵	1.34 X 10 ²¹	2.27X 10⁻⁵
lon implantation 0.025 dpa	473 K	5.7 X 10 ²⁵	9.73 X 10 ²⁰	1.71〉10 ⁻⁵ 1 /times
Un-irradiated W	473 K	6.2 X 10 ²⁵	6.85 X 10 ²⁰	1.10X 10 ⁻⁵

D depth profiling for neutron-irradiated W by NRA



D depth profile for neutron-irradiated W

P50B Masashi Shimada et al. Poster presentation

Estimation of activation energy by D₂⁺ implantation

1 keV D₂⁺ implantation was performed for same W sample and TDS experiment was performed at Shizuoka University.

The desorption stages were almost consistent with D plasma exposure samples, but the peak intensities for each desorption stages were different.



The activation energy for Peak 1 should be much lower than that for Peak 2 (1.48 eV), which would be caused by multi-trapping in a monovacancy.

Estimation of activation energy by D₂⁺ implantation

1 keV D₂⁺ implantation was performed for same W sample and TDS experiment was performed at Shizuoka University.

anistant with D n

The desorption of



The activation energy for Peak 1 should be much lower than that for Peak 2 (1.48 eV), which would be caused by multi-trapping in a monovacancy.

Hydrogen – vacancy binding energy

	Unit : eV		
Ν	E _b (Heinola et al)	E _b (D.F. Johnson et al.)	
1	1.43	1.41	
2	1.41	1.40	
3	1.22	1.14	
4	1.11	1.14	
5	1.00	0.91	
6	0.47	0.79	



FIG. 2. (Color online) Geometries for the lowest-energy sites of three to six hydrogen atoms in a W monovacancy.

If a vacancy is produced, at least 6 H atoms can be trapped simultaneously at a single vacancy.

1 and 2 H atoms are trapped with identical energies,

whereas ensuing H atoms are bound with lower energy.

Enhance D retention

The damaged samples would enhance total D retention and induce the D accumulation.

Additional desorption stage at lower temperature side (Peak 1) in TDS

K. Heinola, et al., Phys. Rev. B 82 (2010) 094102.D. F. Johnson, J. Mater. Res. 25 (2010) 315.

Comparison of TDS spectra for D plasma exposure and D_2^+ ion irradiation



C⁺ and D₂⁺ implantation system at Shizuoka University

10 keV C⁺ imp. : 243 dpa around depth of 15 nm 2.8 MeV Fe²⁺ imp. : 3 dpa around depth of 500 nm (Estimated by TRIM)

Peak temperatures for D_2^+ ion implanted sample were similar for D plasma exposed sample, but the D retention for these peaks were quite different.

Dpa dependence on D retention for D plasma exposed W and D₂⁺ ion irradiated W



D depth profile for neutron irradiated W



D retention for C⁺ implanted W was adjusted by the depth of plasma exposure case. D retentions within 1 nm (D concentration for D plasma exposed W and D_2^+ ion irradiated W) were compared.

D retention clearly increased with increasing of dpa

SEM images for 0.025 dpa Fe²⁺ irradiated tungsten



After D plasma exposure & TDS,

small cracks or pores were introduced which would be formed on the surface by Fe²⁺ irradiation or D plasma exposure.

1,000× 10.0 µm #D:36.4mm

 $5,000 \times \overline{2.00 \,\mu} \,\mathrm{m} \, 2010/09/22$

SEM images for 0.3 dpa Fe²⁺ irradiated tungsten



After D plasma exposure & TDS, the morphology was quite different from that for 0.025 dpa sample. Many cavities and fractions existed in grains, which would induce the peel.

 $1,000 \times 10.0 \,\mu \,\mathrm{m}$ WD:35.3mm

 $5,000 \times 2.00 \,\mu$ m WD:35.3mm



G. M. Wright, et al., Nucl. Fusion 50 (2010) 075006.

TMAP simulation for the desorption of D in neutronirradiated W

Assumptions:

- Simulate previously obtained TDS spectrum at 200 C (0 dpa/0.025 dpa)
- Use 3 segments (0<x_{seg1}<10nm, 10nm <x_{seg2}< 20μm, 20μm<x_{seg3}<200μm)
- Use normalized NRA depth profile up to $< 5^{\circ} \mu m$
- Set very low trap concentration (D/W=10⁻⁶) in deeper bulk (x > 5 μ m)
- Frauenfelder's Diffusivity
- R. Anderl's Recombination Coefficient
- Traps are fully filled with deuterium from surface (saturable traps only)
- Only three different trapping energies in TMAP7 (simulation limitation)



Three different types of traps :

- Low energy trap (0.8-1.2 eV) : dislocation, Vacancy (2nd/3rd D atom)
- Medium energy trap (1.3-1.5 eV) : Vacancy (1st D atom), D₂ molecules from voids
- High energy trap (1.6-2.1 eV) : chemisorptions from voids,

P50B Masashi Shimada et al. Poster presentation

Normalized depth profiles used in TMAP simulation

vacancy cluster

TMAP simulation results



TMAP simulation with higher three traps

P50B Masashi Shimada et al. Poster presentation



Summary of TMAP simulation of TDS spectra for 0.025 dpa neutron-irradiated W

Four (0.9, 1.5, 1.75, 2.0 eV) traps are induced by neutron-irradiation, confirming that different trapping mechanisms exist for neutron-irradiated tungsten.

Monte Carlo code to simulate PWI

<Overview>

- Kinetic Monte Carlo
- Potential energy curve has been derived mainly from DFT calculation results
- 2D periodic boundary conditions
- Deuterium flux: 1 × 10²⁶ D m⁻² s⁻¹
- Temperature: 473 K

<Procedure>

(1) D implantation event
(2) Diffusion events: migration
as D atom in bulk & on surfaces
✓ trapping/detrapping by
vacancies is considered
✓ *R. Frauenfelder's hydrogen diffusivity is used. *J. Vac. Sci. Technol.* 6, 388 (1969).
(3) Desorption events:
recombination desorption as D₂



Comparison of simulated deuterium distribution with deuterium implantation profile and vacancy distribution

Dr. Oda, The University of Tokyo Presented at T conference 2010

Calculation result: influence of vacancy distribution

Dr. Oda, The University of Tokyo Presented at T conference 2010



Influence of vacancy distribution on simulated D distribution

Defects created with ion irradiation and neutron irradiation were simulated by changing the defect distribution.

[ion] Implanted deuterium distribution is similar to defect distribution.

[neutron] Implanted deuterium concentration depends almost linearly on depth.

Conclusions

- The behavior of D retentions for Fe²⁺ irradiated tungsten with the damage of 0.025-3 dpa was compared with that for neutron irradiated tungsten with 0.025 dpa. In addition, surface morphology was clearly changed as the dpa increased.
- The D₂ TDS spectra for Fe²⁺ irradiated tungsten consisted of two desorption stages at 450 K and 550 K although that for neutron irradiated tungsten was composed of three stages and addition desorption stage was found around 750 K.

1st desorption stage : the accumulation of D in mono vacancy
2nd desorption stage : D trapping by intrinsic defects or vacancy
3rd desorption stage : D trapping by void or vacancy cluster (+ diffusion effect)

 D_2 TDS spectra for ion-irradiated tungsten could not represent that for neutron-irradiated one, indicating that the deuterium trapping and desorption mechanism for neutron-irradiated tungsten has a difference from that for ion-irradiated one.

The simulation work represents the multiple D trapping states, especially neutron irradiation case. The difference of vacancy distribution contributes the D trapping profiles, which would influence on D desorption behavior.



Thank you for your attention

This study was supported by JSPS Kakenhi No. 22360389 and 19055002 from MEXT, Japan, and Japan-US collaboration program (TITAN). The TEM observation was performed under the collaboration program at the Institute of Applied Mechanics, Kyushu University.